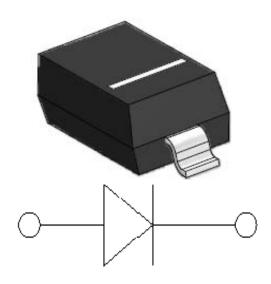




# **High Speed Switching Diode**



#### **Features**

- V<sub>R</sub> 75V
- I<sub>FAV</sub> 250mA

### **Typical Applications**

Extreme fast switches

### **Mechanical Data**

- Package: SOD323
- Terminals: Tin plated leads, solderable per
- J-STD-002 and JESD22-B102
- Polarity: Cathode line denotes the cathode end
- Marking: T5

### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	Conditions	VALUE
DC Blocking Voltage	$V_R$	V	I <sub>R</sub> =100μA	75
Peak forward surge current	I <sub>FSM</sub>	Α	t <sub>p</sub> =1μs	2
Average forward current	I <sub>FAV</sub>	mA		250
Power dissipation	P <sub>tot</sub>	mW		200
Thermal Resistance	R <sub>thJA</sub>	°C/W		625
Maximum junction temperature	T <sub>j</sub>	$^{\circ}$		-55 to +150
Storage temperature range	$T_{stg}$	$^{\circ}$ C		-55 to +150

### **■Electrical Characteristics** (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	Conditions	VALUE
	VF	V	I <sub>F</sub> =5.0mA	0.720
Maximum Facusard vallege			I <sub>F</sub> =10mA	0.855
Maximum Forward voltage			I <sub>F</sub> =100mA	1
			I <sub>F</sub> =150mA	1.25
	IR	nA	V <sub>R</sub> =20V	25
Maximum Reverse current		μΑ	V <sub>R</sub> =25V, T <sub>J</sub> =150 <sup>°</sup> C	30
Maximum Reverse current		nA	V <sub>R</sub> =75V	200
		μΑ	V <sub>R</sub> =75V, T <sub>J</sub> =150℃	50
Minimum Breakdown voltage	$V_R$	V	I <sub>R</sub> =1µA	75
Maximum Diode capacitance	C <sub>D</sub>	pF	$V_R=V_F=0V$ , f =1MH <sub>Z</sub>	4
Maximum Reverse recovery time	t <sub>rr</sub>	ns	$I_F$ =10mA,Irr=0.1 $I_R$ , $R_L$ =100 $\Omega$	4

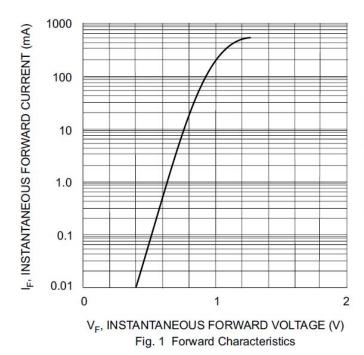


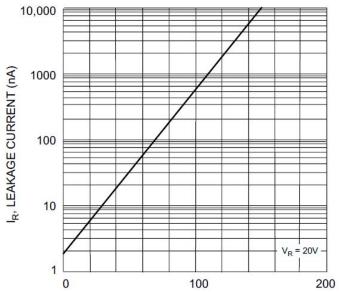
# 1N4448WS

**■Ordering Information** (Example)

PREFERED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
1N4448WS	F2	Approximate 0.004	3000	30000	120000	7" reel

## **■Characteristics** (Typical)



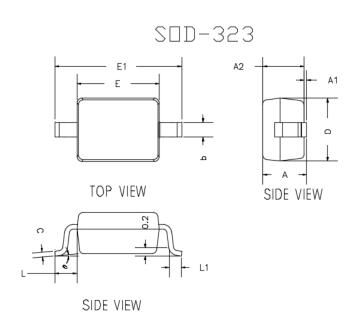


T<sub>j</sub>, JUNCTION TEMPERATURE (°C) Fig. 2 Leakage Current vs Junction Temperature



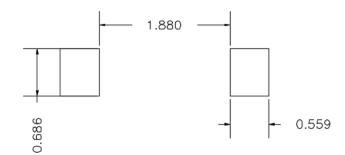


### **■**Outline Dimensions



DIMENSIONS					
DIM	INC	HES	ММ		
	MIN	MAX	MN	MAX	
А		0.0393		1.0000	
A1	0.0000	0.0039	0.0000	0.1000	
A2	0.0314	0.0354	0.8000	0.9000	
lo	0.0098	0.0157	0.2500	0.4000	
С	0.0031	0.0059	0.0800	0.1500	
D	0.0472	0.0551	1,2000	1,4000	
E	0.0629	0.0709	1.6000	1.8000	
E1	0.0984	0.1063	2.5000	2.7000	
L	0.018	7TYP	0.475TYP		
L1	0.0098	0.0157	0.250	0.400	
6	0°	8*	0°	8*	

## **■**Soldering Footprint



UNIT: mm

SUGGESTED SOLDER PAD LAYOUT



### 1N4448WS

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